Learning Based Spatial Power Characterization and Full-Chip Power Estimation for Commercial TPUs

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Outline

- Background of TPU Power Estimation
- Proposed Approach
 - Power map measurement
 - Power map prediction
- Results & Discussion
- Conclusion



- For modern processors, with better performance, the heat produced increases
- Effective thermal control is important
- Accurate spatial power information of the entire chip area benefits the control decision



- Temperature sensors cost space and energy
- Number of on-chip sensors is limited
- E.g., Tensor Processor Unit (TPU)





Tensor Processing Unit (TPU)

- Application-specific integrated circuit (ASIC)
- Designed for machine learning computation
- Unlike GPU No graphics hardware
- More computation power per joule





- Sensors cost space and energy
- Number of on-chip sensors is limited
- E.g., Tensor Processor Unit (TPU)



Only one overall temperature sensor



- Sensors cost space and energy
- Number of on-chip sensors is limited
- E.g., Tensor Processor Unit (TPU)
- Power characterization for TPU is rarely studied



Only one overall temperature sensor



Method

 Characterized TPU power distribution by measuring its surface temperature in thermal steady-state

 Applied machine learning model to establish the relationship between the TPU workload and TPU power map



TPU workload

- TPU workloads consists of
 - 1. A pre-compiled machine learning model
 - 2. Input/output data
- When the model is given, I/O size is fixed, so the workload is uniquely determined
- Model features represents workload





Workload to power map

- Model features represents workload
- Workload determine power distribution
- We can build a connection between model features and power distribution (From now on we call them workload features, to distinguish it from our own model later)





Power map measurement

• We cannot directly measure power distribution

 Instead, we may measure thermal map, then calculate the power map

• Thermal imaging system



Coral Edge TPU



FLIR A325sc

Host board: Intel i7-8650U



Power map measurement

- Run workload
- Measure thermal map
- Convert thermal map to power map
- Feed features and maps to our model





- An approximation approach for chips
- Verified by simulation with a high precision



• Consider the steady state 2D spatial thermal distribution of TPU as T(x, y) $p(x, y) \approx \begin{cases} k[-\nabla^2 T(x, y)] & -\nabla^2 T(x, y) > 0 \\ 0 & -\nabla^2 T(x, y) \le 0 \end{cases}$

with

 $k = \kappa \Delta z$

Where p(x, y) stands for the power density distribution κ and Δz for thermal conductivity and chip thickness



- Noise can be a big problem when calculate ∇^2
- The local correlation of noise is very low, but the real temperature map is smoother
- ∇^2 of noise significantly affect $\nabla^2 T$





Discrete Cosine Transform (DCT)

Convert thermal map to spatial frequency domain

$$D_{uv} = \alpha_u \alpha_v \sum_{x=1}^W \sum_{y=1}^H T(x, y) \cos\left(\frac{\pi(2x-1)u}{2W}\right) \cos\left(\frac{\pi(2y-1)v}{2H}\right), \qquad 0 \le u < W$$

where H, W are the height and width of the map, and

$$\alpha_u = \begin{cases} \sqrt{1/W} & u = 0\\ \sqrt{2/W} & 1 \le u < W \end{cases} \quad \alpha_v = \begin{cases} \sqrt{1/H} & v = 0\\ \sqrt{2/H} & 1 \le v < H \end{cases}$$

- u, v are spatial frequencies along x, y
- $\{D_{uv}\}$ are the DCT frequency coefficients.



- Noise has a high frequency because it has no spatial relevance
- Major information of thermal map is in a few low-frequency coefficients
- We can remove the noise by dropping the high frequency terms

$$T(x,y) = \sum_{u=0}^{W-1} \sum_{v=0}^{H-1} \alpha_u \alpha_v D_{uv} \cos\left(\frac{\pi(2x-1)u}{2W}\right) \cos\left(\frac{\pi(2y-1)v}{2H}\right), \qquad 1 \le x \le W \\ 1 \le y \le H$$

$$T'(x,y) = \sum_{u=0}^{f} \sum_{v=0}^{f} \alpha_u \alpha_v D_{uv} \cos\left(\frac{\pi(2x-1)u}{2W}\right) \cos\left(\frac{\pi(2y-1)v}{2H}\right), \qquad 1 \le x \le W \\ 1 \le y \le H$$





Original thermal map

Remove highfrequency noise

 $-\nabla^2$



Power map



Workload features

- 1. image_shape
- 2. width_multiplier
- 3. depth_multiplier
- 4. pooling_mode
- 5. model_size
- 6. onchip_mem_used
- 7. onchip_mem_remain
- 8. offchip_mem_used
- 9. total num of op
- 10. num of op on TPU
- 11. num of op on CPU
- 12. inference time on TPU
- 13. ADD count
- 14. AVERAGE_POOL_2D count
- 15. CONCATENATION count
- 16. CONV_2D count

- 17. FULLY_CONNECTED count
- 18. DEPTHWISE_CONV_2D count
- 19. L2_NORMALIZATION count
- 20. MAX_POOL_2D count
- 21. MEAN count
- 22. MUL count
- 23. PAD count
- 24. QUANTIZE count
- 25. RESHAPE count
- 26. SOFTMAX count
- 27. SUB count
- 28. RELU count
- 29. REDUCE_MAX count
- 30. STRIDED_SLICE count
- 31. HARD_SWISH count



Machine learning model on TPU

- A machine learning model cannot directly run on TPU
- We need to compile it from CPU version to TPU version
- This process record which operations are supported on TPU, model size, memory usage, ...
- All these features can be collected from the compilation report





Learning-based estimation

- It is difficult for experiments to cover all workloads
- We cannot keep all the workload-map pairs at runtime
- Solution: train a model to estimate power maps





TPU Workloads selection

- Popular image recognition models
- EfficientNet, ResNet, MobileNet, ..., etc.
- 7066 datapoints
- 6359 for training, 707 for testing



Conditional Generative Adversarial Network (CGAN)



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Generator and Discriminator

Generator				
Layer	Kernel	#Output	Activation	
FC	-	8192	Leaky ReLU	
Reshape	-	4x4x512	-	
Conv_trans	5x5	8x8x512	Leaky ReLU	
Conv_trans	5x5	16x16x512	Leaky ReLU	
Conv_trans	5x5	32x32x256	Leaky ReLU	
Conv_trans	5x5	64x64x128	Leaky ReLU	
Conv_trans	5x5	128x128x64	Leaky ReLU	
Conv_trans	5x5	256x256x1	-	





Discriminator				
Layer	Kernel	#Output	Activation	
Conv	5x5	128x128x64	Leaky ReLU	
Conv	5x5	64x64x128	Leaky ReLU	
Conv	5x5	32x32x256	Leaky ReLU	
Conv	5x5	16x16x512	Leaky ReLU	
Conv	5x5	8x8x512	Leaky ReLU	
Conv	5x5	4x4x512	Leaky ReLU	
Conv	5x5	2x2x512	Leaky ReLU	
FC	-	512	Leaky ReLU	
(+Cond)FC	-	256	Leaky ReLU	
FC	-	1	-	



Result metric



Root-Mean-Square Error (RMSE)

$$RMSE = \sqrt{\frac{\sum_{x=1}^{W} \sum_{y=1}^{H} [p(x, y) - p'(x, y)]^2}{W \times H}}$$

where p, p' are the ground truth and the predicted power map H, W are the height and width of the map



Results & Discussion

Power Density RMSE | Average Power Density (unit: mW/mm²) Total Power Percentage Error | Total Power (unit: W)



- Row #1: Measured power density map (unit: W/cm²=10mW/mm²)
- Row #2: Estimated power density map



Result & Discussion

- Average RMSE of power density: 4.98 mW/mm²
- Standard deviation: 2.53 mW/mm²
- Power density range: 0 189.34 mW/mm²
- Average inference time: 6.9ms on Intel Core i7-10710U
- Accurate and fast enough for the real-time power estimation



Conclusion

- Proposed a machine-learning-based approach for real-time estimation of fullchip power maps for commercial Google Coral M.2 TPU chips for the first time.
- Experiment results show that the predictions are accurate, with the RMSE of only 4.98mW/mm², or 2.6% of the full-scale error.
- The inference speed on an Intel Core i7-10710U is as fast as 6.9ms, which is suitable for real-time estimation.

